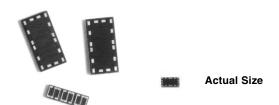
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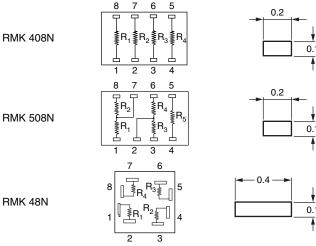


Bare Chip Resistor Network



Manufactured in ULTRAFILM technology, these resistor network chips have a high level of integration, wide ohmic value range, very low temperature coefficient 10 ppm/°C which are unequaled on the market today. Laser trimming can provide excellent precision down to 0.1 % abs 0.01 % ratio.

SCHEMATIC



FEATURES

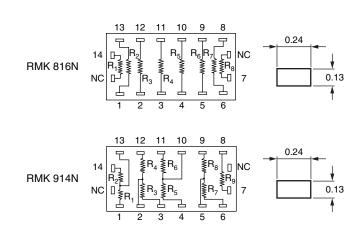
- High precision tolerances down to 0.01 % Ratio
- Very low temperature coefficient: 10 ppm/°C abs., 2 ppm/°C ratio
- Excellent stability < 300 ppm, 2000 h at Pn at + 70 °C
- Wirebondable



ROHS COMPLIANT GREEN

TYPICAL PERFORMANCE

	ABS	TRACKING
TCR	5 ppm/°C	1 ppm/°C
	ABS	RATIO
TOL.	0.1 %	0.01 %



TEST		SPECIFICATIONS	CONDITION
SERIES		48N, 408N, 508N, 816N, 914N	
TCR:	Tracking	± 1 ppm/°C typical/± 2 ppm/°C maximum	- 55 °C to + 125 °C
ICH:	Absolute	± 10 ppm/°C maximum/± 5 ppm/°C maximum	- 55 °C to + 125 °C/0 °C to + 70 °C
Tolerance:	Ratio	± 0.05 %, ± 0.02 %, ± 0.01 %	
	Absolute	± 1.0 %, ± 0.5 %, ± 0.25 %, ± 0.1 %	
Power rating: (0 W at + 155 °C)		48N = 125 mW, others: 250 mW	at + 70 °C
		48N = 50 mW, others: 125 mW	at + 125 °C
Stability		< 300 ppm	2000 h at + 70 °C under Pn
Voltage coeffici	ient	< 0.1 ppm/V	
Working voltage Operating temperature range Storage temperature range Noise Thermal EMF Shelf life stability		100 V	
		- 55 °C to + 155 °C ⁽¹⁾	
		+ 70 °C	
		< - 35 dB	
		0.01 μV/°C	
		50 ppm	1 year at + 25 °C

Note

⁽¹⁾ For 200 °C operations please consult factory

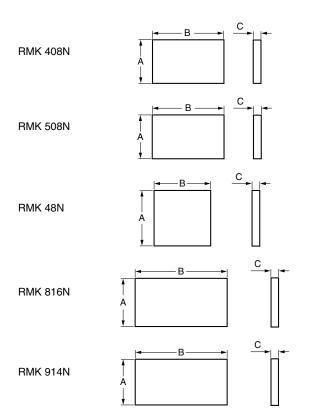
^{*} Please see document "Vishay Green and Halogen-Free Definitions (5-2008)" http://www.vishay.com/doc?99902



RMK 408N, 508N, 48N, 816N, 914N (CN)

Bare Chip Resistor Network

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DIMENSIONS in millimeters	
Α	1.6 ± 0.1
В	2.6 ± 0.1
С	0.4 maximum

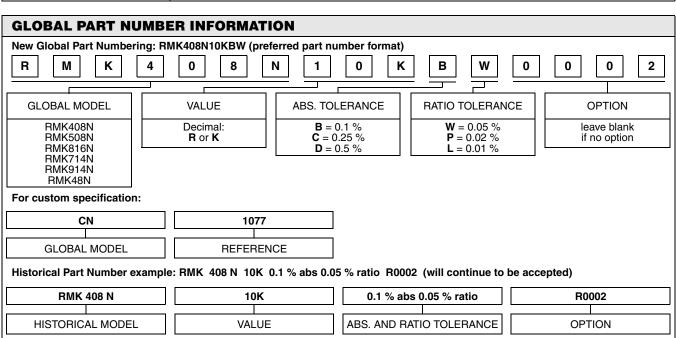
DIMENSIONS in millimeters	
A	1.6 ± 0.1
В	2.6 ± 0.1
С	0.4 maximum

	,
DIMENSIONS in millimeters	
Α	2.1 ± 0.1
В	2.1 ± 0.1
С	0.4 maximum

DIMENSIONS in millimeters	
Α	1.8 ± 0.1
В	3.5 ± 0.1
С	0.4 maximum

DIMENSIONS in millimeters	
A	1.8 ± 0.1
В	3.5 ± 0.1
С	0.4 maximum

MECHANICAL SPECIFICATIONS	
Resistive element	Nichrome
Substrate material	Silicon
Bonding pads	Alumina
Passivation	Silicon Nitride





Vishay

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